imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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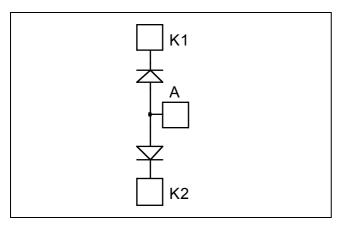


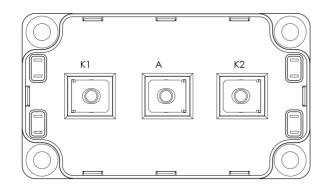


APTDF400AA120G

 $I_{\rm C} = 400 {\rm A}$ (*a*) Tc = 60°C

Dual Common Anode diodes Power Module





Application

• Uninterruptible Power Supply (UPS)

 $V_{RRM} = 1200V$

- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
 - Very low stray inductance - Symmetrical design
- M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit		
V _R	Maximum DC reverse Voltage			1200	V		
V _{RRM}	Maximum Peak Repetitive Revers	e Voltage			1200	v	
I _{F(AV)}	Maximum Average Forward	D () l	500/	$T_C = 25^{\circ}C$	470		
	Current	Duty cycle = :	50%	$T_C = 60^{\circ}C$	400	Δ	
I _{F(RMS)}	RMS Forward Current	Duty cycle = 50%		$T_C = 45^{\circ}C$	500	Π	
I _{FSM}	Non-Repetitive Forward Surge Cu	rrent 8.3	3ms	$T_C = 45^{\circ}C$	3000		

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
\mathbf{V}_{F}	Diode Forward Voltage	$I_F = 400A$			2.4	3.0	
		$I_F = 600A$			2.7		V
		$I_{\rm F} = 400 {\rm A}$	$T_{j} = 125^{\circ}C$		1.8		
I _{RM}	Maximum Reverse Leakage Current	$V_{R} = 1200V$ $\frac{T_{i} = 25^{\circ}C}{T_{j} = 125^{\circ}C}$	$T_i = 25^{\circ}C$			250	۸
			$T_{j} = 125^{\circ}C$			1000	μA
CT	Junction Capacitance	$V_{R} = 1200V$			440		pF

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
t _{rr}	Reverse Recovery Time	$I_{F}=1A, V_{R}=30V$ di/dt = 400A/ μ s	$T_j = 25^{\circ}C$		45		ns
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		385		ns
۲r	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		480		115
Q _{rr}	Reverse Recovery Charge	$I_{\rm F} = 400 {\rm A}$ $V_{\rm R} = 800 {\rm V}$	$T_j = 25^{\circ}C$		4.2		μC
Qrr	Reverse Recovery Charge	$di/dt = 800 \text{ A}/\mu\text{s}$	$T_{j} = 125^{\circ}C$		20.9		μΟ
I	Reverse Recovery Current		$T_j = 25^{\circ}C$		24		А
I _{RRM}	Reverse Recovery Current		$T_j = 125^{\circ}C$		76		Л
t _{rr}	Reverse Recovery Time	$I_{F} = 400A$ $V_{R} = 800V$ $di/dt = 4000A/\mu s$			210		ns
Q _{rr}	Reverse Recovery Charge		$T_j = 125^{\circ}C$		38		μC
I _{RRM}	Reverse Recovery Current				280		А

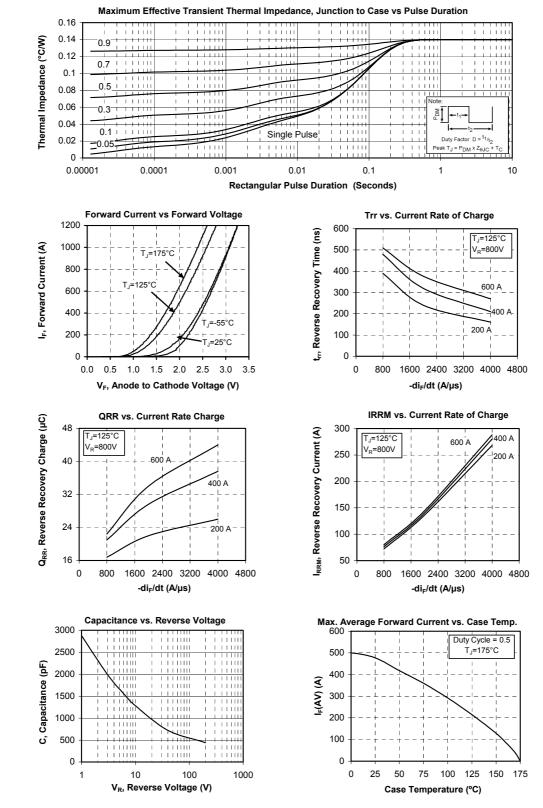
Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit		
R _{thJC}	Junction to Case Thermal Resistance					0.14	°C/W		
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V		
T _J	Operating junction temperature range			-40		175			
T _{STG}	Storage Temperature Range			-40		125	°C		
T _C	Operating Case Temperature					100			
Torque	Mounting torque	To heatsink	M6	3		5	N.m		
	Woulding torque	For terminals	M5	2		3.5	19.111		
Wt	Package Weight					300	g		



APTDF400AA120G

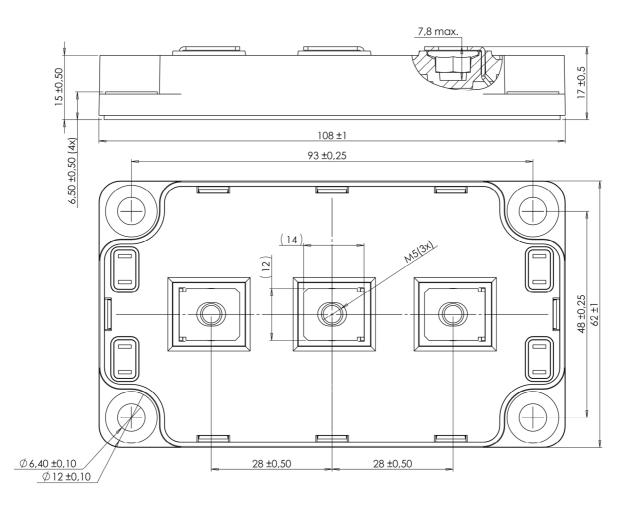
Typical Performance Curve



APTDF400AA120G - Rev 2 October, 2012



SP6 Package outline (dimensions in mm)



APTDF400AA120G - Rev 2 October, 2012



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